

# SEMICONDUCTOR TECHNICAL DATA

### KRC107S~ KRC109S

EPITAXIAL PLANAR NPN TRANSISTOR

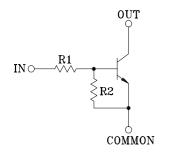
SWITCHING APPLICATION.

INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

#### **FEATURES**

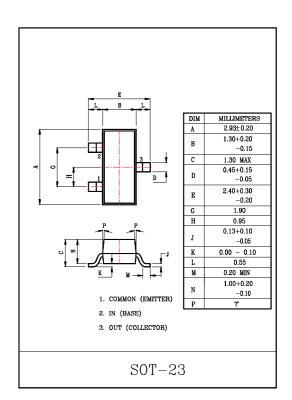
- · With Built-in Bias Resistors.
- · Simplify Circuit Design.
- · Reduce a Quantity of Parts and Manufacturing Process.

#### EQUIVALENT CIRCUIT



#### BIAS RESISTOR VALUES

TYPE NO.	$R1(k\Omega)$	$R2(k\Omega)$
KRC107S	10	47
KRC108S	22	47
KRC109S	47	22



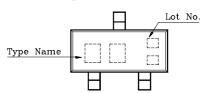
#### MAXIMUM RATINGS (Ta=25℃)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Output Voltage	KRC107S ~109S	$V_{O}$	50	V	
Input Voltage	KRC107S		30, -6	V	
	KRC108S	$V_{\rm I}$	40, -7		
	KRC109S		40,-15		
Output Current		$I_{\mathrm{O}}$	100	mA	
Power Dissipation	KRC107S	$P_{\mathrm{D}}$	200	mW	
Junction Temperature	~109S	T <sub>j</sub>	150	C	
Storage Temperature Range		$T_{ m stg}$	-55 <b>~</b> 150	C	

#### MARK SPEC

TYPE	KRC107S	KRC108S	KRC109S
MARK	NH	NI	NJ





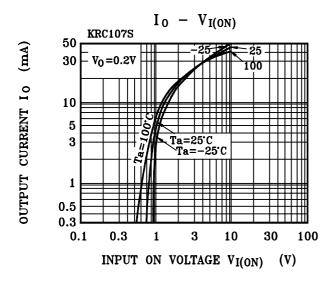
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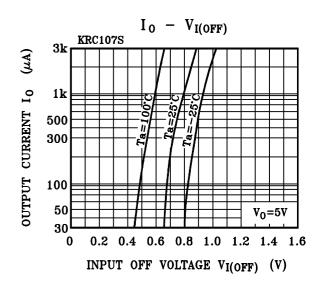
#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

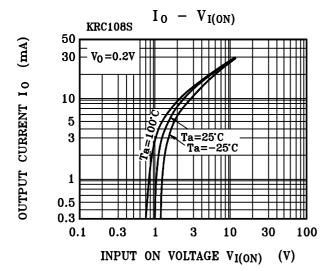
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Output Cut-off Current		KRC107S~109S	$I_{\rm O(OFF)}$	$V_{O}$ =50V, $V_{I}$ =0	-	-	500	nA
DC Current Gain		KRC107S	Gı	V <sub>O</sub> =5V, I <sub>O</sub> =10mA	80	150	-	
		KRC108S			80	150	-	
		KRC109S			70	140	_	
Output Volta	age	KRC107S~109S	$V_{O(ON)}$	I <sub>O</sub> =10mA, I <sub>I</sub> =0.5mA	-	0.1	0.3	V
		KRC107S	V <sub>I(ON)</sub>	V <sub>O</sub> =0.2V, I <sub>O</sub> =5mA	-	1.2	1.8	V
Input Voltag	e (ON)	KRC108S			_	1.8	2.6	
		KRC109S			_	3.0	5.8	
		KRC107S	V <sub>I(OFF)</sub>		0.5	0.75	-	V
Input Votlag	e (OFF)	KRC108S		V <sub>O</sub> =5V, I <sub>O</sub> =0.1mA	0.6	0.88	_	
		KRC109S			1.5	1.82	_	
Transition Frequency		KRC107S~109S	$\mathrm{f_{T}}$ *	$V_O=10V$ , $I_O=5mA$	_	200	_	MHz
		KRC107S			-	-	0.88	
Input Current		KRC108S	$I_{\rm I}$	$V_I$ =5 $V$	-	-	0.36	mA
	KRC109S	-			-	0.16		
	Rise Time	KRC107S	t <sub>r</sub>	$V_{O}$ =5 $V$ , $V_{IN}$ =5 $V$ $R_{L}$ =1 $k\Omega$	_	0.05	_	μS
Switching Time		KRC108S			_	0.12	-	
		KRC109S			_	0.26	-	
	Storage Time	KRC107S	$t_{ ext{slg}}$		_	2.0	_	
		KRC108S			_	2.4	_	
		KRC109S			_	1.5	_	
	Fall Time	KRC107S	$t_{\mathrm{f}}$		_	0.36	_	
		KRC108S			_	0.4	-	
		KRC109S			_	0.41	_	

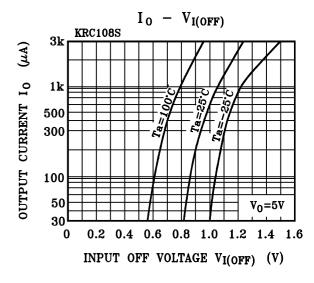
Note: \*Characteristic of Transistor Only

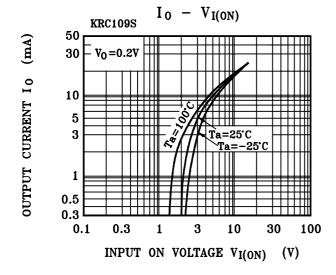
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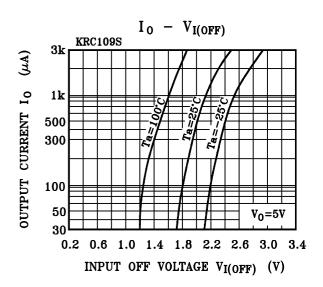












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